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## N-Channel, Depletion-Mode, Vertical DMOS FET

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### Features

- High-input impedance
- Low-input capacitance
- Fast switching speeds
- Low on-resistance
- Free from secondary breakdown
- Low input and output leakages

### Applications

- Normally-on switches
- Battery operated systems
- Voltage to current converters
- Constant current sources
- Current and voltage limiters

### Description

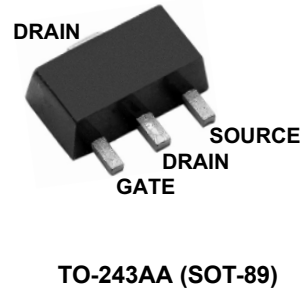
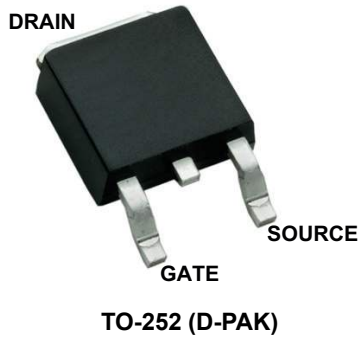
This low threshold, depletion-mode, normally-on, transistor utilizes an advanced vertical Diffusion Metal Oxide Semiconductor (DMOS) structure and a well proven silicon-gate manufacturing process. This combination produces a device with the power-handling capabilities of bipolar transistors, plus the high-input impedance and positive-temperature coefficient inherent in Metal-Oxide Semiconductor (MOS) devices. Characteristic of all MOS structures, this device is free from thermal runaway and thermally-induced secondary breakdown.

Vertical DMOS Field-Effect Transistors (FETs) are ideally suited to a wide range of switching and amplifying applications where a very low threshold voltage, high breakdown voltage, high input impedance, low input capacitance, and fast switching speeds are desired.

# DN2450

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## Package Type



See [Table 2-1](#) for pin information

## 1.0 ELECTRICAL CHARACTERISTICS

### ABSOLUTE MAXIMUM RATINGS†

Drain-to-source voltage.....	BV <sub>DSX</sub>
Drain-to-gate voltage.....	BV <sub>DGX</sub>
Gate-to-source voltage.....	±20V
Operating and storage temperature.....	-55°C to +150°C
Maximum junction temperature.....	150°C

† **Notice:** Stresses above those listed under “Maximum Ratings” may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

### 1.1 ELECTRICAL SPECIFICATIONS

**TABLE 1-1: DC AND AC CHARACTERISTICS**

Electrical Specifications: Unless otherwise specified, for all specifications T <sub>A</sub> = T <sub>J</sub> = +25°C						
Symbol	Parameter	Min	Typ	Max	Units	Conditions
<b>DC Parameters (Note 1, unless otherwise stated)</b>						
BV <sub>DSX</sub>	Drain-to-source breakdown voltage	500	–	–	V	V <sub>GS</sub> = -5.0V, I <sub>D</sub> = 100µA
V <sub>GS(OFF)</sub>	Gate-to-source off voltage	-1.5	–	-3.5	V	V <sub>DS</sub> = 25V, I <sub>D</sub> = 10µA
ΔV <sub>GS(OFF)</sub>	Change in V <sub>GS(OFF)</sub> with temperature	–	–	-4.5	mV/°C	V <sub>DS</sub> = 25V, I <sub>D</sub> = 10µA (Note 2)
I <sub>GSS</sub>	Gate body leakage	–	–	100	nA	V <sub>GS</sub> = ±20V, V <sub>DS</sub> = 0V
I <sub>D(OFF)</sub>	Drain-to-source leakage current	–	–	1.0	µA	V <sub>DS</sub> = BV <sub>DSX</sub> , V <sub>GS</sub> = -10V
		–	–	1.0	mA	V <sub>DS</sub> = 0.8 BV <sub>DSX</sub> , V <sub>GS</sub> = -10V, T <sub>A</sub> = 125°C (Note 2)
I <sub>DSS</sub>	Saturated drain-to-source current	700	–	–	mA	V <sub>GS</sub> = 0V, V <sub>DS</sub> = 25V
R <sub>DS(ON)</sub>	Static drain-to-source on-state resistance	–	7.0	10	Ω	V <sub>GS</sub> = 0V, I <sub>D</sub> = 300mA
ΔR <sub>DS(ON)</sub>	Change in R <sub>DS(ON)</sub> with temperature	–	–	1.1	%/°C	V <sub>GS</sub> = 0V, I <sub>D</sub> = 300mA (Note 2)
<b>AC Parameters (Note 2)</b>						
G <sub>FS</sub>	Forward transconductance	500	–	–	mmho	V <sub>DS</sub> = 10V, I <sub>D</sub> = 300mA
C <sub>ISS</sub>	Input capacitance	–	150	200	pF	V <sub>GS</sub> = -10V, V <sub>DS</sub> = 25V, f = 1MHz
C <sub>OSS</sub>	Common source output capacitance	–	40	55		
C <sub>RSS</sub>	Reverse transfer capacitance	–	15	25		
t <sub>d(ON)</sub>	Turn-on delay time	–	–	15	ns	V <sub>DD</sub> = 25V, I <sub>D</sub> = 300mA, R <sub>GEN</sub> = 25Ω,
t <sub>r</sub>	Rise time	–	–	20		
t <sub>d(OFF)</sub>	Turn-off delay time	–	–	15		
t <sub>f</sub>	Fall time	–	–	15		
<b>Diode Parameters</b>						
V <sub>SD</sub>	Diode forward voltage drop	–	–	1.8	V	V <sub>GS</sub> = -5.0V, I <sub>SD</sub> = 300mA (Note 1)
t <sub>rr</sub>	Reverse recovery time	–	800	–	ns	V <sub>GS</sub> = -5.0V, I <sub>SD</sub> = 300mA (Note 2)

**Note 1:** All DC parameters are 100% tested at 25°C unless otherwise stated. Pulse test: 300 µs pulse, 2% duty cycle.

**2:** Specification is obtained by characterization and is not 100% tested.

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TABLE 1-2: TYPICAL THERMAL RESISTANCE

Package	$\theta_{ja}$
TO-252 (D-PAK)	81°C/W
TO-243AA (SOT-89)	133°C/W

TABLE 1-3: THERMAL CHARACTERISTICS

Package	$I_D^1$ continuous (mA)	$I_D$ pulsed (mA)	Power Dissipation @ $T_A = 25^\circ\text{C}$ (W)	$I_{DR}^1$ (mA)	$I_{DRM}$ (mA)
TO-252 (D-PAK)	350	1000	2.5 <sup>2</sup>	350	1000
TO-243AA (SOT-89)	230	900	1.6 <sup>2</sup>	230	900

1.  $I_D$  continuous is limited by max rated  $T_j$
2. Mounted on FR4 board, 25mm x 25mm x 1.57 mm

## 2.0 PIN DESCRIPTION

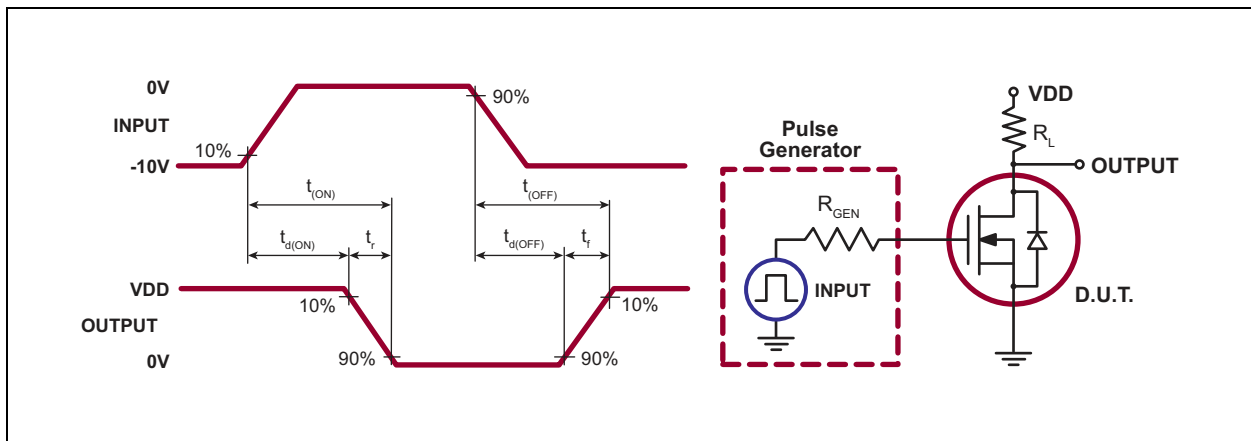
The locations of the pins are listed in [Package Type](#).

TABLE 2-1: PIN DESCRIPTION

Pin # TO-252	Pin # TO-243AA	Function
1	1	GATE
3	3	SOURCE
2,4	2,4	DRAIN

## 3.0 APPLICATION INFORMATION

Figure shows the switching waveform and test circuit for DN2450.



**FIGURE 3-1:** Switching Waveforms and Test Circuit

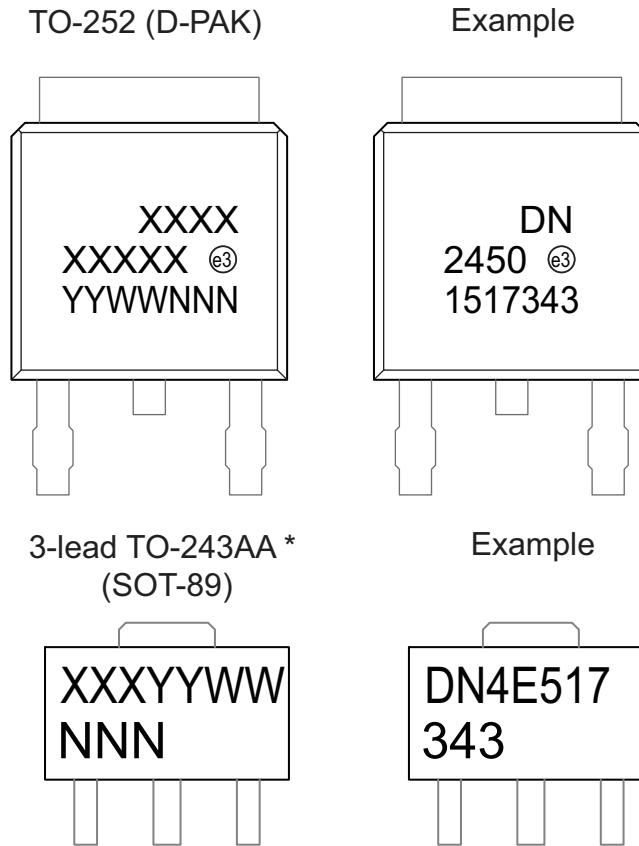
### Product Summary

$BV_{DSX}/BV_{DGX}$ (V)	$R_{DS(ON)}$ (max) ( $\Omega$ )	$I_{DSS}$ (min) (mA)
500	10	700

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## 4.0 PACKAGING INFORMATION

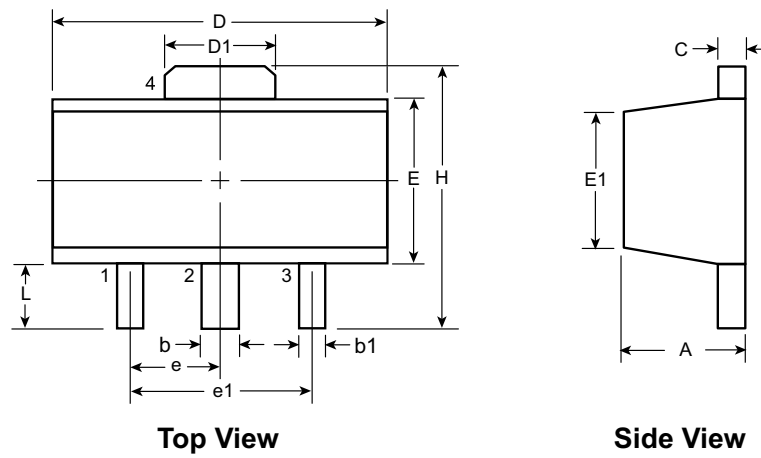
### 4.1 Package Marking Information



<b>Legend:</b>	XX...X	Product Code or Customer-specific information
	Y	Year code (last digit of calendar year)
	YY	Year code (last 2 digits of calendar year)
	WW	Week code (week of January 1 is week '01')
	NNN	Alphanumeric traceability code
	(e3)	Pb-free JEDEC® designator for Matte Tin (Sn)
	*	This package is Pb-free. The Pb-free JEDEC designator (e3) can be found on the outer packaging for this package.

**Note:** In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line, thus limiting the number of available characters for product code or customer-specific information. Package may or not include the corporate logo.

## 3-Lead TO-243AA (SOT-89) Package Outline (N8)



Note: For the most current package drawings, see the Microchip Packaging Specification at [www.microchip.com/packaging](http://www.microchip.com/packaging).

Symbol	A	b	b1	C	D	D1	E	E1	e	e1	H	L		
Dimensions (mm)	MIN	1.40	0.44	0.36	0.35	4.40	1.62	2.29	2.00 <sup>†</sup>	1.50 BSC	3.00 BSC	3.94	0.73 <sup>†</sup>	
	NOM	-	-	-	-	-	-	-	-			-	-	-
	MAX	1.60	0.56	0.48	0.44	4.60	1.83	2.60	2.29			4.25	1.20	

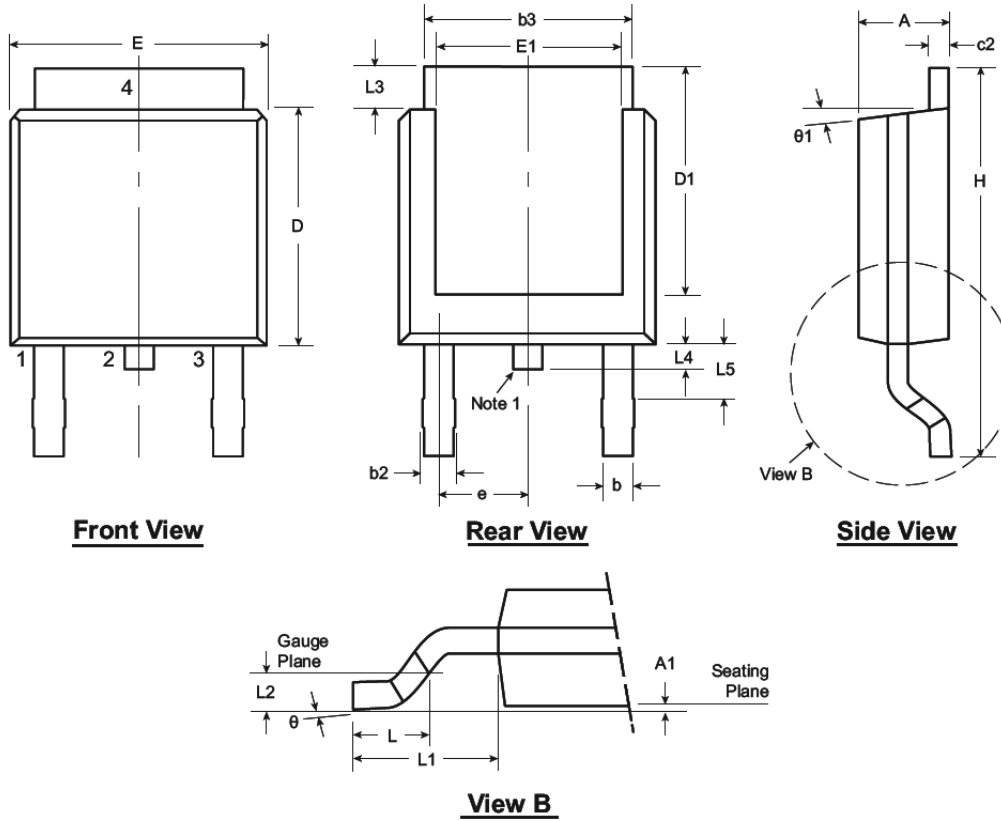
JEDEC Registration TO-243, Variation AA, Issue C, July 1986.

<sup>†</sup> This dimension differs from the JEDEC drawing

Drawings not to scale.

# DN2450

## 3-Lead TO-252 (D-PAK) Package Outline (K4)



Note: For the most current package drawings, see the Microchip Packaging Specification at [www.microchip.com/packaging](http://www.microchip.com/packaging).

**Note:**

1. Although 4 terminal locations are shown, only 3 are functional. Lead number 2 was removed.

Symbol	A	A1	b	b2	b3	c2	D	D1	E	E1	e	H	L	L1	L2	L3	L4	L5	θ	θ1
Dimension (inches)	MIN	.086	.000*	.025	.030	.195	.018	.235	.205	.250	.170	.370	.055			.035	.025*	.035†	0°	0°
	NOM	-	-	-	-	-	.240	-	-	-	.090 BSC	-	.060	.108 REF	.020 BSC	-	-	-	-	-
	MAX	.094	.005	.035	.045	.215	.035	.245	.217*	.265	.200*	.410	.070			.050	.040	.060	10°	15°

JEDEC Registration TO-252, Variation AA, Issue E, June 2004.

\* This dimension is not specified in the JEDEC drawing.

† This dimension differs from the JEDEC drawing.

Drawings not to scale.



## APPENDIX A: REVISION HISTORY

### Revision A (July 2015)

- Update file to new format

# DN2450

## PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

<u>PART NO.</u>	<u>XX</u>	-	<u>X</u>	-	<u>X</u>
Device	Package Options		Environmental		Media Type
Device:	DN2450	=	N-Channel, Depletion-Mode, vertical DMOS FET		
Package:	K4	=	TO-252 (D-PAK)		
	N8	=	TO-243AA (SOT-89)		
Environmental	G	=	Lead (Pb)-free/ROHS-compliant package		
Media Type:	(blank)	=	2000/Reel		

**Examples:**

a) DN2450K4-G TO-252 package, 2000/reel

b) DN2450N8-G TO-243AA package, 2000/reel

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